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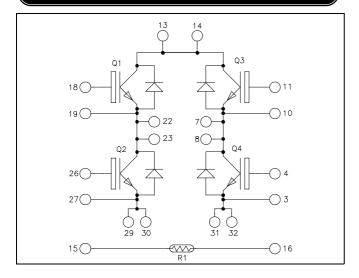


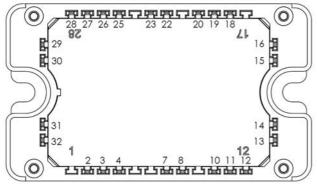






### Full - Bridge Trench + Field Stop IGBT3 Power Module





All multiple inputs and outputs must be shorted together Example: 13/14; 29/30; 22/23 ...

### $V_{CES} = 600V$ $I_C = 100A*$ @ $T_C = 80°C$

#### **Application**

- Welding converters
- Switched Mode Power Supplies
- Uninterruptible Power Supplies
- Motor control

#### **Features**

- Trench + Field Stop IGBT3
  - Low voltage drop
  - Low tail current
  - Switching frequency up to 20 kHz
  - Low leakage current
  - RBSOA and SCSOA rated
- Kelvin emitter for easy drive
- Very low stray inductance
- Internal thermistor for temperature monitoring

#### **Benefits**

- Stable temperature behavior
- Very rugged
- Solderable terminals for easy PCB mounting
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Easy paralleling due to positive TC of VCEsat
- Low profile
- Each leg can be easily paralleled to achieve a phase leg of twice the current capability
- RoHS Compliant

#### All ratings @ $T_i = 25^{\circ}C$ unless otherwise specified

#### Absolute maximum ratings

Symbol	Parameter		Max ratings	Unit
$V_{CES}$	Collector - Emitter Voltage		600	V
T	Continuous Collector Current	$T_C = 25$ °C	150 *	
$I_{C}$	Continuous Conector Current	$T_C = 80$ °C	100 *	A
$I_{CM}$	Pulsed Collector Current	$T_C = 25^{\circ}C$	200	
$V_{GE}$	Gate – Emitter Voltage		±20	V
$P_D$	Power Dissipation	$T_C = 25$ °C	340	W
RBSOA	Reverse Bias Safe Operating Area	$T_j = 150$ °C	200A @ 550V	

<sup>\*</sup> Specification of device but output current must be limited due to size of output pins.

CAUTION: These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed.



#### **Electrical Characteristics**

Symbol	Characteristic	Test Conditions	Min	Typ	Max	Unit	
$I_{CES}$	Zero Gate Voltage Collector Current	$V_{GE} = 0V, V_{CE} = 600V$				250	μΑ
<b>V</b>	Collector Emitter Saturation Voltage	$V_{GE} = 15V$	$T_j = 25$ °C		1.5	1.9	17
$V_{\text{CE(sat)}}$	Conector Emitter Saturation Voltage	$I_{\rm C} = 100 A$	$T_j = 150$ °C		1.7		·
$V_{GE(th)}$	Gate Threshold Voltage	$V_{GE} = V_{CE}$ , $I_C = 1.5 \text{ mA}$		5.0	5.8	6.5	V
$I_{GES}$	Gate – Emitter Leakage Current	$V_{GE} = 20V, V_{CE} = 0V$				400	nA

**Dynamic Characteristics** 

·	Characteristic	Test Condition	ns	Min	Typ	Max	Unit
Cies	Input Capacitance	$V_{GE} = 0V$ $V_{CE} = 25V$			6100		
$C_{oes}$	Output Capacitance				390		pF
$C_{res}$	Reverse Transfer Capacitance	f = 1MHz		190			
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (25°C) $V_{GE} = \pm 15V$ $V_{Bus} = 300V$ $I_{C} = 100A$			115		
$T_{\rm r}$	Rise Time				45		ns
T <sub>d(off)</sub>	Turn-off Delay Time				225		
$T_{\mathrm{f}}$	Fall Time	$R_G = 3.3\Omega$		55			
$T_{d(on)}$	Turn-on Delay Time	Inductive Switching (150°C) $V_{GE} = \pm 15V$ $V_{Bus} = 300V$ $I_{C} = 100A$ $R_{G} = 3.3\Omega$			130		
T <sub>r</sub>	Rise Time				50		
$T_{d(off)}$	Turn-off Delay Time				300		ns
$T_{\mathrm{f}}$	Fall Time				70		
Eon	Turn on Energy	$V_{GE} = \pm 15V$ $V_{Bus} = 300V$ $I_C = 100A$ $R_G = 3.3\Omega$	$T_j = 150$ °C		0.875		mJ
$E_{\text{off}}$	Turn off Energy		$T_j = 150$ °C		3.5		mJ
$R_{\text{thJC}}$	Junction to Case Thermal Resistance					0.44	°C/W

Reverse diode ratings and characteristics

Symbol	Characteristic Test Conditions			Min	Typ	Max	Unit
$V_{RRM}$	Peak Repetitive Reverse Voltage					600	V
$I_{RM}$	Reverse Leakage Current	$V_R=600V$				250	μΑ
$I_F$	DC Forward Current		$Tc = 80^{\circ}C$		100		A
$V_{\mathrm{F}}$	Diode Forward Voltage	$I_F = 100A$	$T_j = 25^{\circ}C$		1.6	2	V
<b>v</b> <sub>F</sub>		$V_{GE} = 0V$	$T_j = 150$ °C		1.5		V
4	t <sub>rr</sub>   Reverse Recovery Time   -		$T_j = 25$ °C		125		
$\iota_{rr}$		$T_j = 150$ °C		220		ns	
	Daviana Dagayany Changa	overy Charge $ \begin{array}{c} I_F = 100A \\ V_R = 300V \\ di/dt = 2000A/us \end{array} $	$T_j = 25$ °C		4.7		
Qrr	Reverse Recovery Charge		$T_j = 150$ °C		9.9		μС
E	D D E		$T_j = 25$ °C		1.1		Т
$E_{r}$	Reverse Recovery Energy		$T_j = 150$ °C		2.4		mJ
$R_{\text{thJC}}$	Junction to Case Thermal Resistance					0.77	°C/W



Temperature sensor NTC (see application note APT0406 on www.microsemi.com for more information).

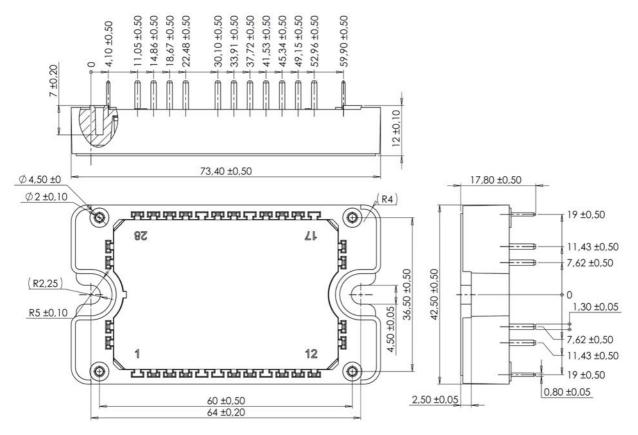
Symbol	Characteristic		Min	Тур	Max	Unit
R <sub>25</sub>	Resistance @ 25°C			50		kΩ
$\Delta R_{25}/R_{25}$				5		%
B <sub>25/85</sub>	$T_{25} = 298.15 \text{ K}$			3952		K
$\Delta \mathrm{B/B}$		T <sub>C</sub> =100°C		4		%

$$R_T = \frac{R_{25}}{\exp\left[B_{25/85}\left(\frac{1}{T_{25}} - \frac{1}{T}\right)\right]}$$
 T: Thermistor temperature R<sub>T</sub>: Thermistor value at T

#### Thermal and package characteristics

Symbol	Characteristic			Min	Max	Unit
$V_{ISOL}$	RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz			4000		V
$T_{J}$	Operating junction temperature range			-40	175	
$T_{\text{JOP}}$	Recommended junction temperature under switching conditions			-40	T <sub>J</sub> max -25	°C
$T_{STG}$	Storage Temperature Range			-40	125	
$T_{\rm C}$	Operating Case Temperature			-40	125	
Torque	Mounting torque	To heatsink	M4	2	3	N.m
Wt	Package Weight				110	g

#### Package outline (dimensions in mm)

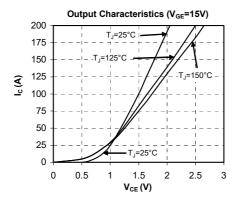


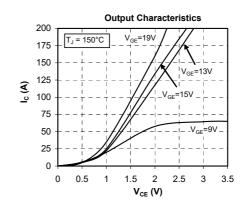
See application note 1906 - Mounting Instructions for SP3F Power Modules on <a href="www.microsemi.com">www.microsemi.com</a>

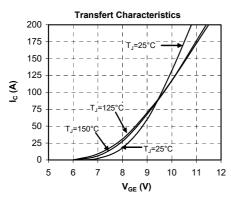
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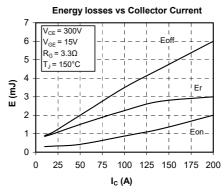


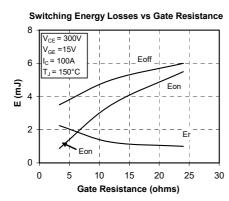
#### **Typical Performance Curve**

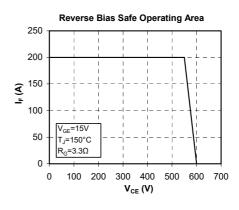


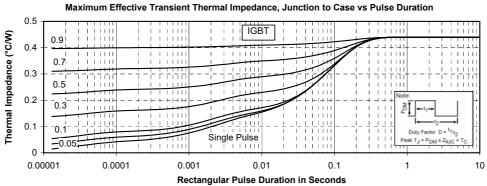














20

0

0

switching

25

50

75

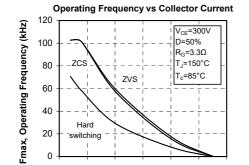
I<sub>C</sub> (A)

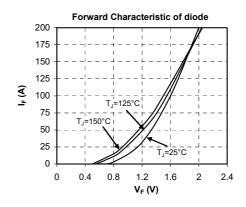
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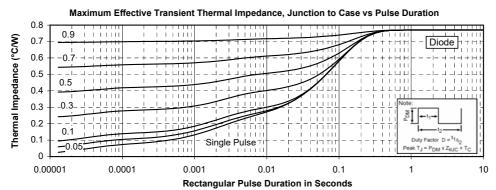
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150

# APTGT100H60T3G









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